1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Surface-Mounted Device (SMD) package.

2. Features and benefits

- Average forward current I_{F(AV)} ≤ 0.2 A
- Reverse voltage V_R ≤ 20 V
- Low forward voltage typ. V_F = 245 mV
- Low reverse current typ. I_R = 5 μA
- · Ultra small and leadless SMD package
- Package height typ. 0.3 mm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- LED backlight for mobile application

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current	δ = 0.5 ; f = 20 kHz; T_{amb} = 115 °C; square wave	[1]	-	-	0.2	Α
		δ = 0.5 ; f = 20 kHz; T_{sp} = 125 °C; square wave		-	-	0.2	А
V_R	reverse voltage	T _j = 25 °C		-	-	20	V
V _F	forward voltage	I_F = 10 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C		-	245	310	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C		-	5	-	μΑ

 $\label{eq:continuous} \textbf{[1]} \quad \text{Device mounted on a ceramic Printed-Circuit Board (PCB), } \textbf{Al}_2\textbf{O}_3, \text{ standard footprint.}$





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		1 - 2
2	Α	anode		sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

^[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

•	Type number	Package		
		Name	Description	Version
	PMEG2002AESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG2002AESF	A

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T _j = 25 °C		-	20	V
I _F	forward current	T _{sp} ≤ 120 °C		-	0.28	Α
I _{F(AV)}	average forward current	δ = 0.5 ; f = 20 kHz; T_{amb} = 115 °C; square wave	[1]	-	0.2	А
		δ = 0.5 ; f = 20 kHz; T _{sp} = 125 °C; square wave		-	0.2	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.25$		-	2	Α
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	4.5	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	325	mW

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Symbol	Parameter	Conditions		Min	Max	Unit
			[3]	-	525	mW
			[1]	-	950	mW
Tj	junction temperature			-	125	°C
T _{amb}	ambient temperature			-55	125	°C
T _{stg}	storage temperature			-65	150	°C

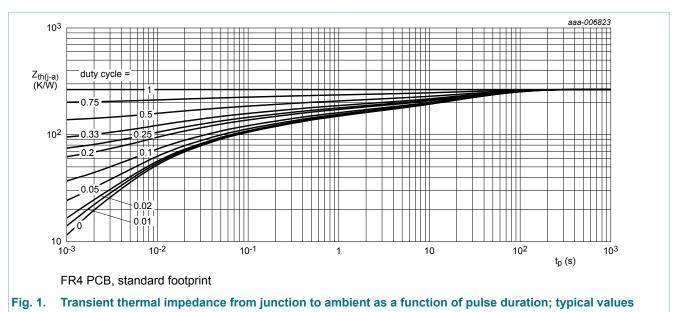
- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

9. Thermal characteristics

Table 6. Thermal characteristics

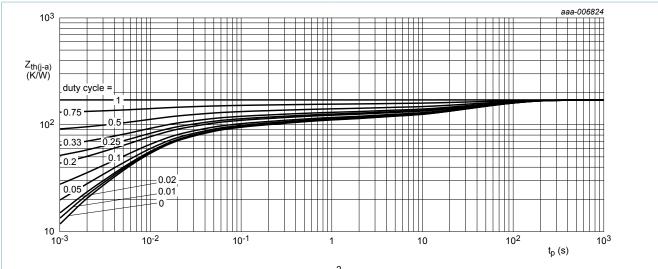
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance		[1][2]	-	-	310	K/W
	from junction to ambient		[1][3]	-	-	190	K/W
			[1][4]	-	-	105	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	40	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.



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FR4 PCB, mounting pad for anode and cathode 1 cm² each

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

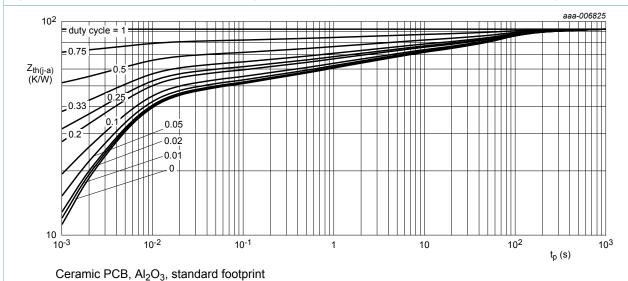


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I_F = 0.1 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	120	180	mV
		I_F = 1 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	180	250	mV
		I_F = 10 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	245	310	mV
		I_F = 100 mA; pulsed; $t_p \le$ 300 μs; $δ \le$ 0.02 ; T_j = 25 °C	-	330	380	mV
		I_F = 200 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$; T_j = 25 °C	-	375	420	mV
I _R	reverse current	V _R = 6 V; T _j = 25 °C	-	3.2	20	μA
		V _R = 10 V; T _j = 25 °C	-	5	-	μA
		V _R = 20 V; T _j = 25 °C	-	10	45	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	25	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	10	-	pF
t _{rr}	reverse recovery time	I_F = 200 mA; I_R = 200 mA; $I_{R(meas)}$ = 40 mA; T_j = 25 °C	-	1.9	-	ns

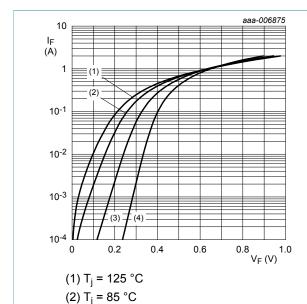
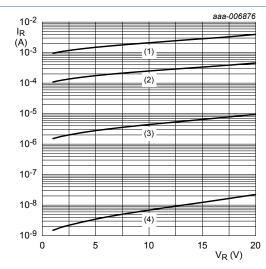


Fig. 4. Forward current as a function of forward voltage; typical values

(3) $T_j = 25 \, ^{\circ}C$

(4) $T_i = -40 \, ^{\circ}C$



- (1) $T_i = 125 \,^{\circ}C$
- (2) $T_i = 85 \, ^{\circ}C$
- (3) $T_j = 25 \, ^{\circ}C$
- (4) $T_j = -40 \, ^{\circ}C$

Fig. 5. Reverse current as a function of reverse voltage; typical values

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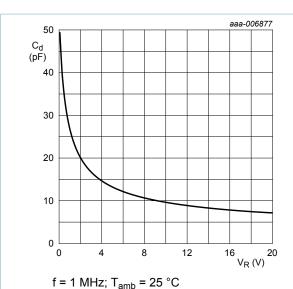
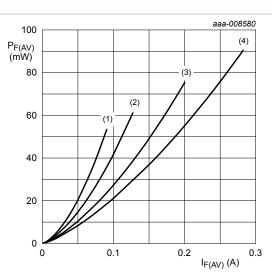


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



 $T_j = 125$ °C

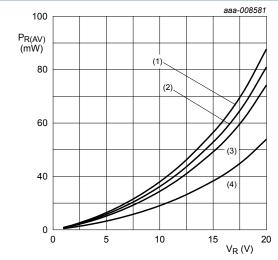
 $(1) \delta = 0.1$

(2) $\delta = 0.2$

 $(3) \delta = 0.5$

 $(4) \delta = 1$

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



T_i = 125 °C

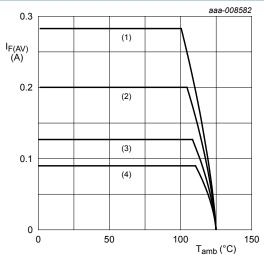
 $(1) \delta = 1 (DC)$

(2) δ = 0.9; f = 20 kHz

(3) δ = 0.8; f = 20 kHz

(4) δ = 0.5; f = 20 kHz

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

 $T_j = 125 \,{}^{\circ}\text{C}$

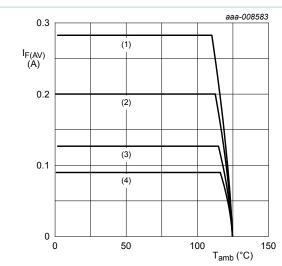
 $(1) \delta = 1$

 $(2) \delta = 0.5$

 $(3) \delta = 0.2$

 $(4) \delta = 0.1$

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for anode and cathode 1

cm² each

T_i = 125 °C

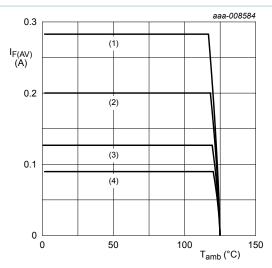
 $(1) \delta = 1$

 $(2) \delta = 0.5$

 $(3) \delta = 0.2$

 $(4) \delta = 0.1$

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

 $T_i = 125 \,{}^{\circ}\text{C}$

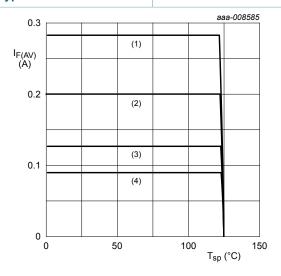
 $(1) \delta = 1$

(2) $\delta = 0.5$

 $(3) \delta = 0.2$

 $(4) \delta = 0.1$

Fig. 11. Average forward current as a function of ambient temperature; typical values



T_i = 125 °C

 $(1) \delta = 1$

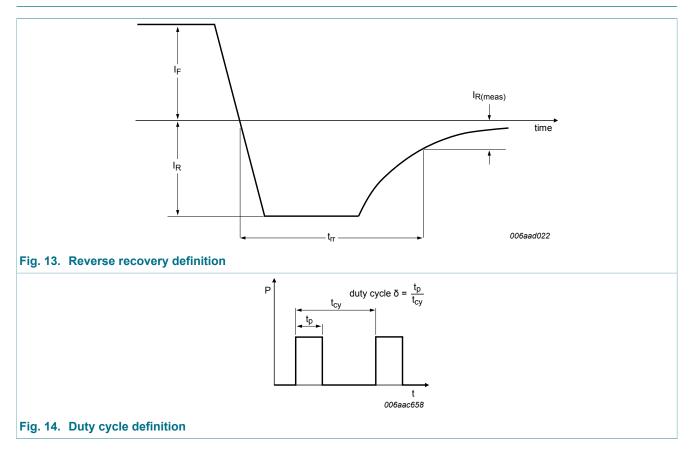
 $(2) \delta = 0.5$

 $(3) \delta = 0.2$

 $(4) \delta = 0.1$

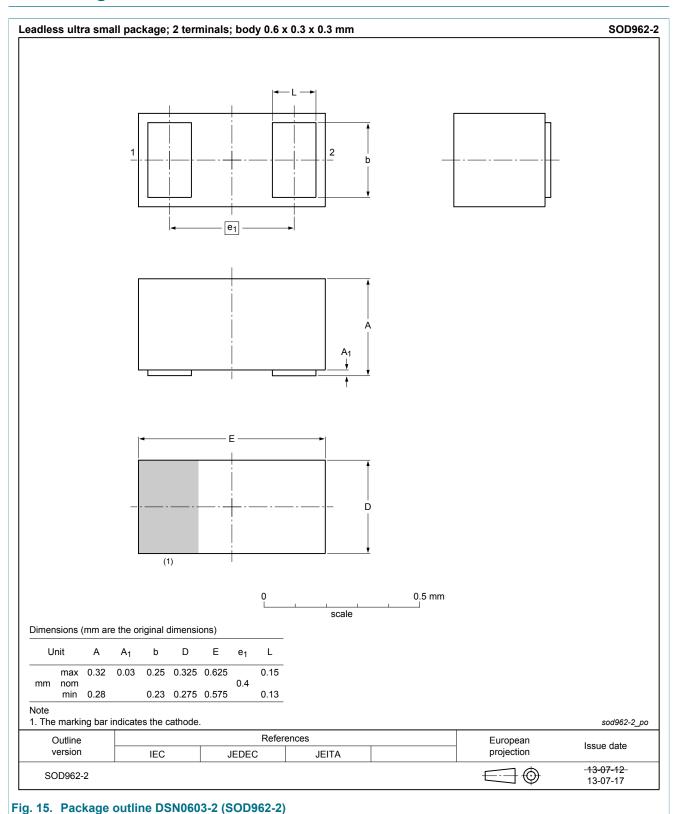
Fig. 12. Average forward current as a function of solder point temperature; typical values

11. Test information



The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

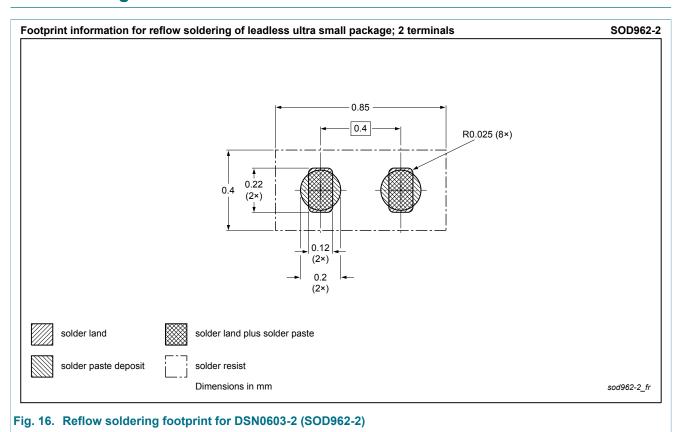
12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG2002AESF v.3	20140122	Product data sheet	-	PMEG2002AESF v.2		
Modifications:	 Features and benef 	Features and benefits: corrected				
PMEG2002AESF v.2	20131008	Product data sheet	-	PMEG2002AESF v.1		
PMEG2002AESF v.1	20130301	Objective data sheet	-	-		

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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